		L #	Hits	Search Text	DBs	Time Stamp
	1	L1 Frim	24	03386" "6203613" "6203927" "641 6870" "6492038" "6503330" "6585 823").PN.	,	2006/06/17 13:53
	2	L2	_	(427/566,567,569- 577,595,596,597,248.1- 255.7),CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:00
/	3	L3	4263	(427/567,570,576,585,597,249.15,249.17,255.29,255.31,255.32,25	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:00
	74	m L4		(427/566,567,569- 577,585,595,596,597,248.1- 255.7).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:01
	5	L5		(ALD (atomic Mono) near (layer deposit deposition) monolayer	IP. PLIT II PLIT	2006/06/17 14:04
	6	L6	1903	pentoxide) Ta2O5 "Ta.sub.2O.sub.5" "Ta.sub.2 O.sub.5") with (grain crystal\$7	EPO; JPO;	2006/06/17 14:07
	7	L7	3980	pentoxide) Ta2O5 "Ta.sub.2O.sub.5" "Ta.sub.2 O.sub.5") same (grain crystal\$7	EPO; JPO;	2006/06/17 14:08

10/759.810

		L #	Hits	Search Text	DBs	Time Stamp
L24 L25	8	L8	16	il gun s''i with larain		2006/06/17 14:09
	9	L9	2455937	Si3N4 "Si.sub.x C" "Si sub 3N sub 4" "Si sub 3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:16
LILE	10		5 rut L 16	L9 same L8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:14
	11	L11	1604	L9 same L7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:14
	12	L12	652	L9 same L6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:15
	13	L13	2204	"SiN.m/c." SiC Si3N4 "Si.sub.x C" "Si.sub.3N.sub.4" "Si.sub.3 N.sub.4" "Si.sub.xN.sub.v"	14'D() • .1D() •	2006/06/17 14:16
	14	L14	3392	(aluminum Al hafnium Hf) adj (oxide dioxide) Al2O3 HfO2 "Al.sub.2O.sub.3" "HfO.sub.2"	H: D(1 • . D(1 •	2006/06/17 14:20

	L #	Hits	Search Text	DBs	Time Stamp
15	L15	0	L10 same (L13 or L14)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:22
16	L16 (L10 and (L13 or L14) 2005/0158590AH	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:21
17		,	L8 and (L13 or L14) not L16	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:21
18	L18	5	L12 same (L13 or L14) not L16	16'0/10 .10(1)	2006/06/17 14:22
19	L19 (1371	L12 and (L13 or L14) not (L16		2006/06/17 14:23
20	L20 (11 / /	L11 same (L13 or L14) not (L16 or L18 or L19)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:23
21	L21	7 1	Lll and (L13 or L14) not (L16 or L18 or L19 or L20)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:25

4

	L#	Hits	Search Text	DBs	Time Stamp
22	L22(1	L8 and L5 and L4	14'D() • .1D() •	2006/06/17 14:25
23	L23	\rightarrow	L8 and L5 and L4 (not L16	IH: D() • . I D() •	2006/06/17 14:26
24	L24 (L8 and L4 not L16	IH D() • . D() •	2006/06/17 14:26
25	^{L25} (14	L8 not (L16 or L24)	IL'U()• .IU()•	2006/06/17 14:28
26	L26	0	L19 and L4		2006/06/17 14:28
27	L27	0	L20 and L4	IH: D() • . I D() •	2006/06/17 14:28
28	L28 (2		IH. PU 1 - 1 PU 1 -	2006/06/17 14:28



	L #	Hits	Search Text	DBs	Time Stamp
29	L29 (51	L21 not L28	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:29
30	L30 ((14) M	(("5100847") or ("6159553") or ("6582779") or ("6350404") or ("6699604") or ("6861164") or ("6887594")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 14:38

		L #	Hits	Search Text	DBs	Time Stamp
	29	L19	32	L12 and (L13 or L14) not (L16		2006/06/17 16:07
	30	L20	11.7	L11 same (L13 or L14) not (L16 or L18 or L19)		2006/06/17 17:17
/	31	L29	51	L21 not L28	IH: D() • . I D() •	2006/06/17 18:48
	32	L32	[7]	L7 same (EBPDV EB (E electron)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	2006/06/17 18:51
	33	L33	32	L32 and (L11 or L12)		2006/06/17 18:51
	34	L34 (14 (1))	L33 not (L16 or L18 or L19 or L20 or L28 or L29)	H'D(10 . D(10	2006/06/17 18:53

Day : Saturday Date: 6/17/2006

Time: 14:33:29



Inventor Name Search Result

Your Search was:

Last Name = LI

First Name = CHIEN-WEI

Application#	Patent#	Status	Date Filed	Title	Inventor Name
07297530	Not Issued	16x	01/17/1989	SUPER TOUGH MONOLITHIC SILICON NITRIDE DESCRIPTION OF THE INVENTION	LI, CHIEN-WEI
07450899	Not Issued	161/	12/14/1989	SUPER TOUGH MONOLITHIC SILICON NITRIDE	LI, CHIEN-WEI
07576330	Not Issued	166	08/31/1990	SUPER TOUCH MONOLITHIC SILICON NITRIDE	LI, CHIEN-WEI
<u>0</u> 7716142	Not Issued	166	06/17/1991	HIGH TOUGHNESS-HIGH STRENGTH SINTERED SILICON NITRIDE	LI, CHIEN-WEI
07759970	5100847	150	09/17/1991	SUPER TOUGH MONOLITHIC SILICON NITRIDE	LI, CHIEN-WEI
07860958	Not Issued	166	03/31/1992	MONOLITHIC SILICON NITRIDE HAVING HIGH FRACTURE TOUGHNESS	LI, CHIEN-WEI
07863581	Not Issued	166	04/09/1992	SINTERED SILICON NITRIDE OF HIGH TOUGHNESS, STRENGTH AND RELIABILITY	LI, CHIEN-WEI
08075930	Not Issued	161	06/14/1993	MONOLITHIC SILICON NITRIDE HAVING HIGH FRACTURE TOUGHNESS	LI, CHIEN-WEI
08076940	5312788	150	*	HIGH TOUGHNESS, HIGH STRENGTH SINTERED SILICON NITRIDE	LI, CHIEN-WEI
08096203	5637540	150		SINTERED SILICON NITRIDE OF HIGH TOUGHNESS, STRENGTH AND RELIABILITY	LI, CHIEN-WEI
08168439	5449649	150	4	MONOLITHIC SILICON NITRIDE HAVING HIGH FRACTURE TOUGHNESS	LI, CHIEN-WEI

08257598 08789699	5494866	11			
00700600		150		STRESS-RUPTURE RESISTANT SINTERED SILICONNITRIDE	LI, CHIEN-WEI
<u>08789099</u>	5759933	150	01/27/1997	GAS PRESSURE SINTERED SILICON NITRIDE HAVING HIGH STRENGTH AND STRESS RUPTURE RESISTANCE	LI, CHIEN-WEI
09208109	6159553	150		THERMAL BARRIER COATING FOR SILICON NITRIDE	LI, CHIEN-WEI
09371826 (6582779)150	08/11/1999	SILIC <u>ON NIT</u> RIDE COMPONENTS WITH PROTECTIVE COATING	LI, CHIEN-WEI
09592320	6350404	150		Method for producing a ceramic part with an internal structure	LI, CHIEN-WEI
09595791	6415376	150	7,	APPARATUS AND METHOD FORISSUE GROUPING OF INSTRUCTIONS IN A VLIW PROCESSOR	LI, CHIEN-WEI
09598015	6699604	150	า	PROTECTIVE COATING INCLUDING POROUS SILICION NITRIDE MATRIX AND NOBLE METAL	LI, CHIEN-WEI
09990640	6861164	130	11/21/2001	ENVIRONMENTAL AND THERMAL BARRIER COATING FOR CERAMIC COMPONENTS	LI, CHIEN-WEI
10085437	6684320	150	3	APPARATUS AND METHOD FOR ISSUE GROUPING OF INSTRUCTIONS IN A VLIW PROCESSOR	LI, CHIEN-WEI
10085724	Not Issued	93		AREA AND POWER EFFICIENT VLIW PROCESSOR WITH IMPROVED SPEED	LI, CHIEN-WEI
10621168	6977233	150	07/15/2003 ×	SINTERED SILICON NITRIDE	LI, CHIEN-WEI
18621719	Not Issued	161 abd		Environmental & thermal barrier coating	LI, CHIEN-WEI
10644523	Not Issued	71		Diffusion barrier coating for sibased components	LI, CHIEN-WEI
10682752	Not Issued	93 Allo		BRAZE-BASED PROTECTIVE COATING FOR SILICON NITRIDE	LI, CHIEN-WEI
10719629	Not Issued	71		Oxidation barrier coatings for silicon based ceramics	LI, CHIEN-WEI
10759810	Not Issued	71		Atomic layer deposition for turbine components	LI, CHIEN-WEI
10085437 10085724 10621168 10621719 10644523 10682752	6861164 Not Issued Not Issued	150 150 93 150 161 401 71	02/28/2002 \(\) 02/28/2002 \(\) 02/28/2002 \(\) 07/15/2003 \(\) 07/16/2003 \(\) 10/08/2003 \(\) 01/16/2004	INCLUDING POROUS SILICION NITRIDE MATRIX AND NOBLE METAL ENVIRONMENTAL AND THERMAL BARRIER COATING FOR CERAMIC COMPONENTS APPARATUS AND METHOD FOR ISSUE GROUPING OF INSTRUCTIONS IN A VLIW PROCESSOR AREA AND POWER EFFICIENT VLIW PROCESSOR WITH IMPROVED SPEED SINTERED SILICON NITRIDE Environmental & thermal barrier coating Diffusion barrier coating for si- based components BRAZE-BASED PROTECTIVE COATING FOR SILICON NITRIDE Oxidation barrier coatings for silicon based ceramics Atomic layer deposition for turbine	LI, CHIEN-WEI LI, CHIEN-WEI LI, CHIEN-WEI LI, CHIEN-WEI LI, CHIEN-WEI LI, CHIEN-WEI

			_			
טוי	10773373	6887594	50	02/05/2004	ENVIRONMENTAL AND THERMAL BARRIER COATING FOR CERAMIC COMPONENTS	LI, CHIEN-WEI
	10982445	Not Issued	30 un 940	11/05/2004	Protective coating for ceramic components	LI, CHIEN-WEI
	11127522	Not Issued	30		Ternary carbide and nitride materials having tribological applications and methods of making same	LI, CHIEN-WEI
	11127524	Not Issued	30	05/10/2005	Ternary_carbide and nitride composites having tribological applications and methods of making same	LI, CHIEN-WEI
	11216877	Not Issued	30	08/30/2005	Sintered silicon nitride	LI, CHIEN-WEI
	60278102	Not Issued	159		Environmental and thermal barrier coating for ceramic components	LI, CHIEN-WEI
	60575040	Not Issued	159	05/26/2004	Ternary metal carbides-silver composite materials for tribological applications	LI, CHIEN-WEI
	60575041	Not Issued	159		Novel carbide materials for tribological applications	LI, CHIEN-WEI
	60740172	Not Issued	20		Ruthenium precursors and intermediates for deposition processes, their production and method of use	LI, CHIEN-WEI
	60740206	Not Issued	20	11/28/2005	Ruthenium precursors and intermediates for plasma-enhanced ALD	LI, CHIEN-WEI

Inventor Search Completed: No Records to Display.

Search Another: In	Last Name	First Name	
Search Another: In	LI	CHIEN-WEI	Search

To go back use Back button on your browser toolbar.

Back to PALM | ASSIGNMENT | OASIS | Home page